

Vishay General Semiconductor

# PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



PRIMARY CHARACTERISTICS					
$V_{BR}$	6.8 V to 43 V				
P <sub>PPM</sub>	400 W				
$P_{D}$	1.0 W				
I <sub>FSM</sub>	40 A				
T <sub>J</sub> max.	185 °C				

### **TYPICAL APPLICATIONS**

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs. MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive and telecommunication.

### **FEATURES**

Junction passivation optimized design passivated anisotropic rectifier technology



 T<sub>J</sub> = 185 °C capability suitable for high reliability and automotive requirement

Available in uni-directional polarity only

- 400 W peak pulse power capability with a 10/1000 μs waveform, repetitive rate (duty cycle): 0.01 %
- Excellent clamping capability
- · Very fast response time
- · Low incremental surge resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- · Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### **MECHANICAL DATA**

Case: MPG06, molded epoxy over passivated junction Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	LIMIT	UNIT				
Peak power dissipation with a 10/1000 µs waveform <sup>(1)</sup> (fig. 1)	P <sub>PPM</sub>	400	W				
Peak pulse current with a 10/1000 μs waveform <sup>(1)(2)</sup> (fig. 3)	I <sub>PPM</sub>	See next table	Α				
Power dissipation on infinite heatsink at $T_L = 75$ °C (fig. 5)	P <sub>D</sub>	1.0	W				
Peak forward surge current 8.3 ms single half sine-wave (2)	I <sub>FSM</sub>	40	Α				
Maximum instantaneous forward voltage at 25 A (2)	V <sub>F</sub>	3.5	V				
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 185	°C				

#### Notes:

(1) Non-repetitive current pulse, per fig. 3 and derated above T<sub>A</sub> = 25 °C per fig. 2

<sup>(2)</sup> Measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum

## **TMPG06-6.8 thru TMPG06-43A**

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)									
DEVICE TYPE	BREAK VOLTAG	IMUM (DOWN E V <sub>BR</sub> <sup>(1)</sup> <sub>T</sub> (V)	TEST CURRENT I <sub>T</sub> (mA)	STAND- OFF VOLTAGE V <sub>WM</sub>	MAXIMUM REVERSE LEAKAGE AT V <sub>WM</sub>	REVERSE LEAKAGE AT V <sub>WM</sub> T <sub>J</sub> = 150 °C	PEAK PULSE CURRENT I <sub>PPM</sub> <sup>(2)</sup>	MAXIMUM CLAMPING VOLTAGE AT I <sub>PPM</sub>	MAXIMUM TEMP. COEFFICIENT OF V <sub>BR</sub>
	MIN.	MAX.	1 ()	(V)	I <sub>D</sub> (μA)	Ι <sub>D</sub> (μΑ)	(A)	V <sub>C</sub> (V)	(%/°C)
TMPG06-6.8 (4)	6.12	7.48	10.0	5.50	300	1000	27.8	10.8	0.057
TMPG06-6.8A (4)	6.45	7.14	10.0	5.80	300	1000	28.6	10.5	0.057
TMPG06-7.5 (4)	6.75	8.25	10.0	6.05	150	500	25.6	11.7	0.060
TMPG06-7.5A (4)	7.13	7.88	10.0	6.40	150	500	26.5	11.3	0.061
TMPG06-8.2 (4)	7.38	9.02	10.0	6.63	50.0	200	24.0	12.5	0.065
TMPG06-8.2A (4)	7.79	8.61	10.0	7.02	50.0	200	24.8	12.1	0.065
TMPG06-9.1 <sup>(4)</sup>	8.19	10.0	1.0	7.37	10.0	50.0	21.7	13.8	0.068
TMPG06-9.1A (4)	8.65	9.55	1.0	7.78	10.0	50.0	22.4	13.4	0.068
TMPG06-10	9.00	11.0	1.0	8.10	5.0	20.0	26.7	15.0	0.073
TMPG06-10A	9.50	10.5	1.0	8.55	5.0	20.0	27.6	14.5	0.073
TMPG06-11	9.90	12.1	1.0	8.92	2.0	10.0	24.7	16.2	0.075
TMPG06-11A	10.5	11.6	1.0	9.40	2.0	10.0	25.6	15.6	0.075
TMPG06-12	10.8	13.2	1.0	9.72	1.0	5.0	23.1	17.3	0.076
TMPG06-12A	11.4	12.6	1.0	10.2	1.0	5.0	24.0	16.7	0.078
TMPG06-13	11.7	14.3	1.0	10.5	1.0	5.0	21.1	19.0	0.081
TMPG06-13A	12.4	13.7	1.0	11.1	1.0	5.0	22.0	18.2	0.081
TMPG06-15	13.5	16.3	1.0	12.1	1.0	5.0	18.2	22.0	0.084
TMPG06-15A	14.3	15.8	1.0	12.8	1.0	5.0	18.9	21.2	0.084
TMPG06-16	14.4	17.6	1.0	12.9	1.0	5.0	17.0	23.5	0.086
TMPG06-16A	15.2	16.8	1.0	13.6	1.0	5.0	17.8	22.5	0.086
TMPG06-18	16.2	19.8	1.0	14.5	1.0	5.0	15.1	26.5	0.088
TMPG06-18A	17.1	18.9	1.0	15.3	1.0	5.0	15.9	25.5	0.088
TMPG06-20	18.0	22.0	1.0	16.2	1.0	5.0	13.7	29.1	0.090
TMPG06-20A	19.0	21.0	1.0	17.0	1.0	5.0	14.4	27.7	0.090
TMPG06-22	19.8	24.2	1.0	17.8	1.0	5.0	12.5	31.9	0.092
TMPG06-22A	20.9	23.1	1.0	18.8	1.0	5.0	13.1	30.6	0.092
TMPG06-24	21.6	26.4	1.0	19.4	1.0	5.0	11.5	34.2	0.094
TMPG06-24A	22.8	25.2	1.0	20.5	1.0	5.0	12.0	33.2	0.094
TMPG06-27	24.3	29.7	1.0	21.8	1.0	5.0	10.2	39.1	0.096
TMPG06-27A	25.7	28.4	1.0	23.1	1.0	5.0	10.7	37.5	0.096
TMPG06-30	27.0	33.0	1.0	24.3	1.0	5.0	9.2	43.5	0.097
TMPG06-30A	28.5	31.5	1.0	25.6	1.0	5.0	9.7	41.4	0.097
TMPG06-33	29.7	36.3	1.0	26.8	1.0	5.0	8.4	47.7	0.098
TMPG06-33A	31.4	34.7	1.0	28.2	1.0	5.0	8.8	45.7	0.098
TMPG06-36	32.4	39.6	1.0	29.1	1.0	5.0	7.7	52.0	0.099
TMPG06-36A	34.2	37.8	1.0	30.8	1.0	5.0	8.0	49.9	0.099
TMPG06-39	35.1	42.9	1.0	31.6	1.0	5.0	7.1	56.4	0.100
TMPG06-39A	37.1	41.0	1.0	33.3	1.0	5.0	7.4	53.9	0.100
TMPG06-43	38.7	47.3	1.0	34.8	1.0	5.0	6.5	61.9	0.101
TMPG06-43A	40.9	45.2	1.0	36.8	1.0	5.0	6.7	59.3	0.101

<sup>(1)</sup> Pulse test: t<sub>p</sub> ≤ 50 ms
(2) Surge current waveform per fig. 3 and derated per fig. 2
(3) All terms and symbols are consistent with ANSI/IEEE C62.35
(4) TMPG06-6.8(A) thru TMPG06-9.1(A) not recommended for new design due to product be end of life on 31-May-11 per PCN-PDD-008-2010 Rev. 0



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ORDERING INFORMATION (Example)						
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE E		BASE QUANTITY	DELIVERY MODE			
TMPG06-6.8AHE3/54 (1)	0.218	54	5500	13" diameter paper tape and reel		

#### Note

#### **RATINGS AND CHARACTERISTICS CURVES**

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$ 

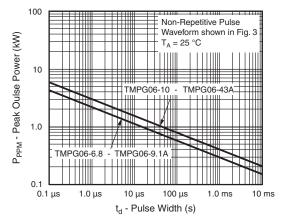


Figure 1. Peak Pulse Power Rating Curve

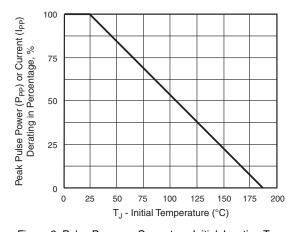


Figure 2. Pulse Power or Current vs. Initial Junction Temperature  $\label{eq:current} % \begin{center} \begin{$ 

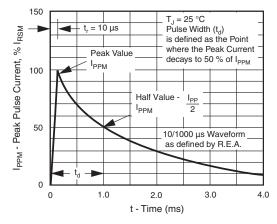


Figure 3. Pulse Waveform

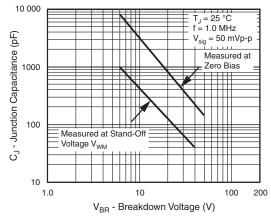


Figure 4. Typical Junction Capacitance

<sup>(1)</sup> AEC-Q101 qualified

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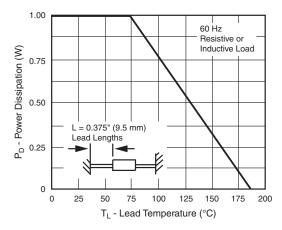


Figure 5. Power Derating Curve

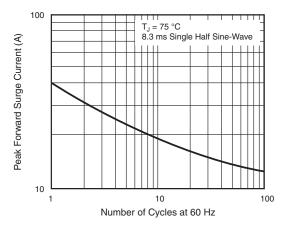
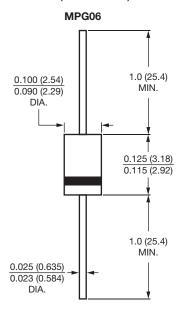


Figure 6. Maximum Non-Repetitive Forward Surge Current

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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